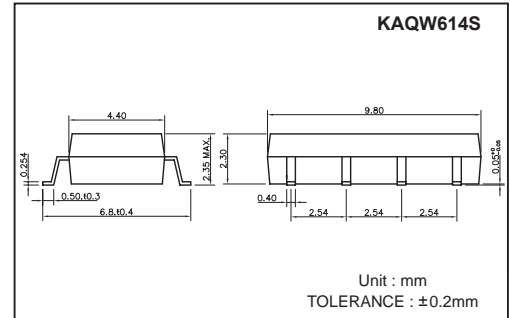


Features

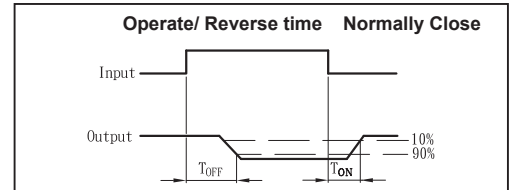
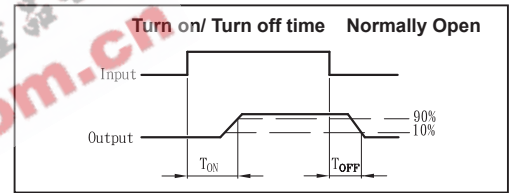
1. Normally Open and Close, Single Pole Single Throw
2. Control 400VAC or DC Voltage
3. Switch 130mA Loads
4. LED control Current, 5mA
5. Low ON-Resistance
6. dv/dt , >500V/ms
7. Isolation Test Voltage, 1500VACrms



Absolute Maximum Ratings

($T_a=25^\circ\text{C}$)

Emitter (Input)	
Reverse Voltage	5.0V
Continuous Forward Current	50mA
Peak Forward Current	1A
Power Dissipation	100mW
Derate Linearly from 25°C	1.3mW/°C
Detector (Output)	
Output Breakdown Voltage	±400V
Continuous Load Current	±130mA
Power Dissipation	500mW
General Characteristics	
Isolation Test Voltage	1500VACrms
Isolation Resistance $V_{io}=500V, T_a=25^\circ\text{C}$	$\geq 10^{10}\Omega$
Total Power Dissipation	550mW
Derate Linearly from 25°C	2.5mW/°C
Storage Temperature Range	-40°C to +125°C
Operating Temperature Range	-30°C to +85°C
Junction Temperature	100°C
Soldering Temperature, 2mm from case, 10 sec.....	260°C



Electro-optical Characteristics

(Ta=25°C)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Emitter (Input)						
Forward Voltage	V _F	I _F = 10mA		1.8	2.0	V
Operation Input Current	I _{FON(N.O)} I _{FON(N.C)}	V _L = ±20V, I _L = 100mA (N.O) V _L = ±20V, I _L ≤ 5μA (N.C) t = 10ms			5	mA
Recovery Input Current	I _{FON(N.O)} I _{FON(N.C)}	V _L = ±20V, I _L ≤ 5μA (N.O) V _L = ±20V, I _L = 100mA (N.C) t = 10ms	0.2			mA

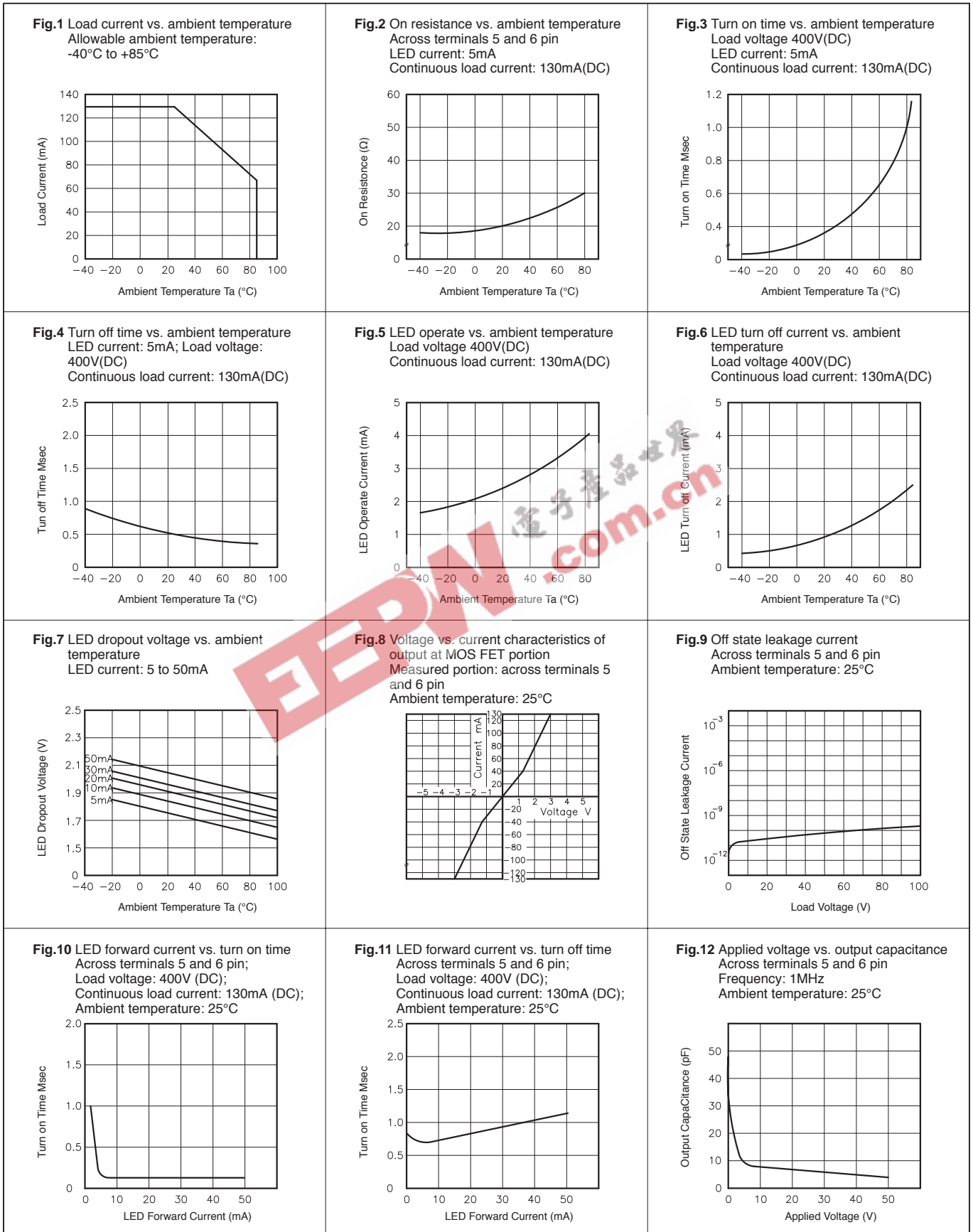
Detector (Output) normally open						
Output Breakdown Voltage	V _B	I _B = 50μA	400			V
Output Off-State Leakage	I _{TOFF}	V _T = 100V, I _F = 0mA		0.2	1	μA
I/O Capacitance	C _{ISO}	I _F = 0, f = 1MHz		6		pF
ON Resistance	R _{ON}	I _L = 100mA, I _F = 10mA		20	30	Ω
Turn-On Time	T _{ON}	I _F = 10mA, V _L = ±20V		0.3	1.0	ms
Turn-Off Time	T _{OFF}	t = 10ms, I _L = ±100mA		0.7	1.5	ms

Detector (Output) normally close						
Output Breakdown Voltage	V _B	I _B = 50μA	400			V
Output Off-State Leakage	I _{TOFF}	V _T = 100V, I _F = 0mA		0.2	2	μA
I/O Capacitance	C _{ISO}	I _F = 0, f = 1MHz		6		pF
ON Resistance	R _{ON}	I _L = 100mA, I _F = 10mA		40	50	Ω
Reverse (ON) Time	T _{ON}	I _F = 10mA, V _L = ±20V		0.6	1.5	ms
Operate (OFF) Time	T _{OFF}	t = 10ms, I _L = ±100mA		0.3	1.0	ms

Mos Relay Schematic and Wiring Diagrams

Type	Schematic	Output configuration	Load	Connection	Wiring Diagrams
KAQW614S		1a1b	AC/DC	-	<p>(1) Two independent 1 Form A & 1 Form B use</p> <p>(2) 1 Form A & 1 Form B use</p>

Data Curve (KAQW614S Normally Open Characteristics)



Data Curve (KAQW614S Normally Close Characteristics)

